Burhani

SOLAR PANELS

BHF 3W

Solar Panels Features And Benefits Manufactured from high quality multicrystalline silicon wafers Uniform surface morphology through isotropic texturization Emitter deposition in a metal-free roller furnace Uniform blue anti-reflection coating to enhance wide spectral response Metallization through highly automated printing line with world-class vision system ensuring best print quality through auto-paste dispenser Edge isolation by laser ablation technique 100% sorting for both visual and electrical parameters using class A sorter

Manufacturing Excellence

Proprietary wafer inspection system to carry out 100% incoming wafer inspection to ensure highest wafer to cell yield Inline integrated quality control and monitoring Highly safe operating conditions through automated Chemical Dosing System (CDS)

Automated cell sorting into 32 separate bins based on IEC 609041 guidelines



Quality Standards

100% inspection for reverse current, shunt resistance and series resistance 100% inspection for visual and optical defects such as cracks or holes, finger interruption, rear bus bar interruption, missing Aluminium print per cell, and surface contamination Cells calibrated to reference cells from Fraunhofer ISE cell lab, Germany, traceable to NIST standard Bar-coded packaging to facilitate complete "wafer to cell" electronic data trai

TECHNICAL PARAMETERS	BURHANI PV MODULE	
ELECTRICAL CHARACTERISTICS	SS-3	SS-3A
Nominal Power (Pm) in Watts	3	3
Open Circuit Voltage (Voc) in Volts	21.0	10.0
Short Circuit Current (Isc) in Amps	0.19	0.38
Voltage at Maximum Power (Vmp) in Volts	17.0	8.80
Current at Maximum Power (Imp) In Amps	0.18	0.34
Maximum System Voltage	600V	600V
PHYSICAL PARAMETERS		
Solar Cells per Module (Units)	36	18
Length X Width X Thickness (LXWXT) in mm	255X185X22	185X185X22
In Inches	10.0X7.3X0.8	7.3X7.3X0.8
Weight in Kg	0.75	0.65
Mounting Holes Pitch(Y) in mm	127.50	92.50
In Inches	5.0	3.6
Mounting Holes Pitch(X) in mm	155	155
In Inches	6.1	6.1
Area in Sq. Meter	0.05	0.03
In Sq. Feet	0.54	0.32
Junction Box	IP 65	IP 65
OTHER CHARACTERISTICS		
Type of cell	Mono / Multi crystalline Silicone	
Front Face	Tempered Glass (Low Iron)	
Encapsulate	EVA (Ethylene Vinyl Acetate)	
Frame	Anodized Aluminium	
Junction Box	Weather Proof Nylon 6	
Temp. Coefficient	Voltage:	-0.123 V/°K
	Current:	+4.4mA / °K
	Power:	-0.47%/°K
NOCT	47 +/- 2 °C	

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